

MMBT4401T

### NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

### **Features**

- BV<sub>CEO</sub> > 40V
- I<sub>C</sub> = 600mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMBT2907AT
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.002 grams (Approximate)

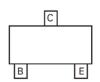
SOT523



Top View



**Device Schematic** 



Package Pin Out Configuration

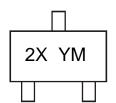
## **Ordering Information** (Note 4)

I	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
	MMBT4401T-7-F	AEC-Q101	2X	7	8	3.000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



 $\begin{aligned} 2X &= \text{Product Type Marking Code (See Ordering Information)} \\ YM &= \text{Date Code Marking} \\ Y \text{ or } \overline{Y} &= \text{Year (ex: } F = 2018) \\ M &= \text{Month (ex: } 9 = \text{September)} \end{aligned}$ 

Date Code Key

Year	2018	2019	2020	2021	2022	2 202	23 2	024	2025	2026	2027	2028
Code	F	G	Н	I	J	K	(	L	M	N	0	Р
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# **Absolute Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Collector Current	Ic	600	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	833	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

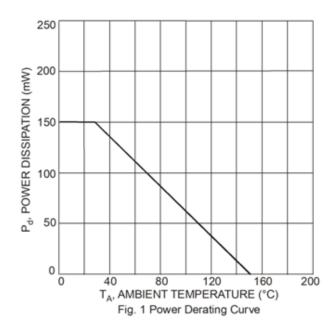
## ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

## **Thermal Characteristics and Derating Information**



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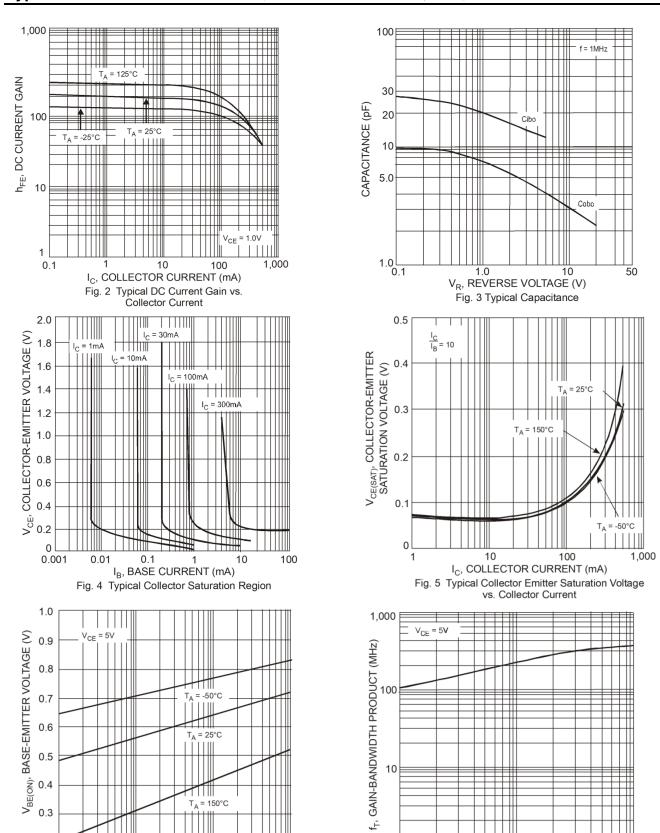
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60	_	V	$I_C = 100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	40	_	V	$I_C = 1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	6	_	V	$I_E = 100 \mu A, I_C = 0$
Collector Cutoff Current	I <sub>CEX</sub>		100	nA	$V_{CE} = 35V, V_{EB(OFF)} = 0.4V$
Base Cutoff Current	$I_{BL}$	_	100	nA	$V_{CE} = 35V$ , $V_{EB(OFF)} = 0.4V$
ON CHARACTERISTICS (Note 7)			•		
		20 40	_		$I_C = 100\mu A, V_{CE} = 1V$ $I_C = 1.0mA, V_{CE} = 1V$
DC Current Gain	h <sub>FE</sub>	80	_	_	Ic = 10mA, V <sub>CE</sub> = 1V
		100	300		$I_{\rm C} = 150 {\rm mA}, V_{\rm CE} = 1 {\rm V}$
		40	_		I <sub>C</sub> = 500mA, V <sub>CE</sub> = 2V
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.4 0.75	V	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	0.75	0.95 1.2	V	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
SMALL SIGNAL CHARACTERISTICS			l		10 = 0001111 (, 1B = 001111 (
Output Capacitance	$C_{ m obo}$	_	6.5	pF	$V_{CB} = 5V, f = 1.0MHz, I_E = 0$
Input Capacitance	C <sub>ibo</sub>		30	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$
Input Impedance	h <sub>ie</sub>	1	15	kΩ	
Voltage Feedback Ratio	h <sub>re</sub>	0.1	8.0	x 10 <sup>-4</sup>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1mA,
Small Signal Current Gain	h <sub>fe</sub>	75	375	_	f = 1MHz
Output Admittance	h <sub>oe</sub>	1	30	μS	
Current Gain-Bandwidth Product	f <sub>T</sub>	250	_	MHz	$V_{CE} = 20V, I_{C} = 20mA,$ f = 100MHz
SWITCHING CHARACTERISTICS					
Delay Time	t <sub>D</sub>	_	15	ns	V <sub>CC</sub> = 30V, I <sub>C</sub> = 150mA,
Rise Time	t <sub>R</sub>	_	20	ns	$V_{BE(OFF)} = 2V, I_{B1} = 15mA$
Storage Time	t <sub>S</sub>	_	225	ns	V <sub>CC</sub> = 30V, I <sub>C</sub> = 150mA
Fall Time	t <sub>F</sub>		30	ns	$I_{B1} = -I_{B2} = 15\text{mA}$

Notes: 7. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



10 I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 7 Typical Gain-Bandwidth Product vs. Collector Current

10

I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 6 Typical Base-Emitter Voltage vs. Collector Current

100

0.2

0.1

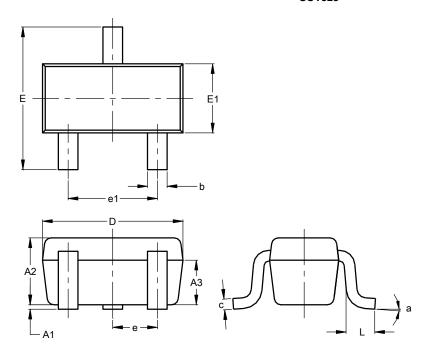
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## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT523**

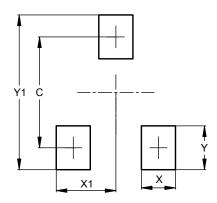


SOT523						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.60	0.80	0.75			
A3	0.45	0.65	0.50			
b	0.15	0.30	0.22			
C	0.10	0.20	0.12			
D	1.50	1.70	1.60			
Е	1.45	1.75	1.60			
E1	0.75	0.85	0.80			
е		0.50 BS	С			
e1	0.90	1.10	1.00			
Г	0.20	0.40	0.33			
а	0°		8°			
Al	I Dimen	sions ir	n mm			

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT523



Dimensions	Value (in mm)			
	(111 111111)			
С	1.29			
Х	0.40			
X1	0.70			
Y	0.51			
Y1	1.80			



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